

PUMB11/ZLF Datasheet



DiGi Electronics Part Number

PUMB11/ZLF-DG

Manufacturer

Nexperia USA Inc.

Manufacturer Product Number

PUMB11/ZLF

Description

TRANS PREBIAS

Detailed Description

Pre-Biased Bipolar Transistor (BJT) 2 PNP - Pre-Biased (Dual) 50V 100mA 180MHz 300mW Surface Mou

nt 6-TSSOP

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Manufacturer Product Number:	Manufacturer:
PUMB11/ZLF	Nexperia USA Inc.
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
2 PNP - Pre-Biased (Dual)	100mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50V	10kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10kOhms	30 @ 5mA, 5V
V 5 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
Vce Saturation (Max) @ lb, lc:	Current - Collector Cutoff (Max):
vce Saturation (Max) @ Ib, Ic: 150mV @ 500μA, 10mA	TμA
150mV @ 500μA, 10mA	1μΑ
150mV @ 500μA, 10mA Frequency - Transition:	1μA Power - Max:
150mV @ 500μA, 10mA Frequency - Transition: 180MHz	1μA Power - Max: 300mW
150mV @ 500μA, 10mA Frequency - Transition: 180MHz Grade:	1μA Power - Max: 300mW Qualification:
150mV @ 500μA, 10mA Frequency - Transition: 180MHz Grade: Automotive	1μA Power - Max: 300mW Qualification: AEC-Q101
150mV @ 500μA, 10mA Frequency - Transition: 180MHz Grade: Automotive Mounting Type:	1μA Power - Max: 300mW Qualification: AEC-Q101 Package / Case:

Environmental & Export classification

0000.00.0000

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	OBSOLETE
HTSUS:	



PUMB11

PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

1 October 2022

Product data sheet

1. General description

PNP/PNP double Resistor-Equipped Transistor (RET) in a very SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PUMD3
NPN/NPN complement: PUMH11

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- · Reduces component count
- · Reduces pick and place costs

3. Applications

- Low current peripheral drivers
- · Control of IC inputs
- · Replaces general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	П6 П5 П4	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2		
6	01	output (collector) TR1	☐1 ☐2 ☐3 TSSOR((SOT262)	╽╶┼┼┼┼
			TSSOP6 (SOT363)	GND1 I1 O2
				006aaa212

6. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
PUMB11		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMB11	B%1

[1] % = placeholder for manufacturing site code

PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

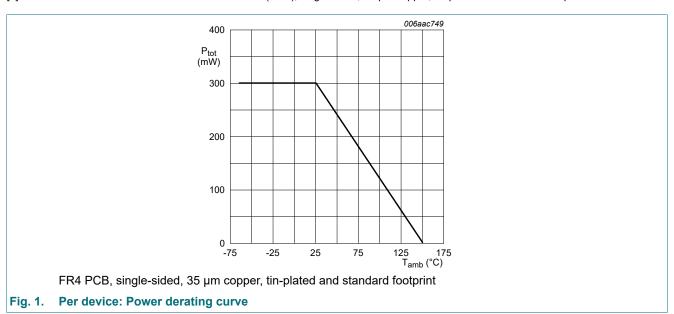
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or				'	
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-10	V
VI	input voltage	positive		-	10	V
		negative		-	-40	V
Io	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device				'		
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

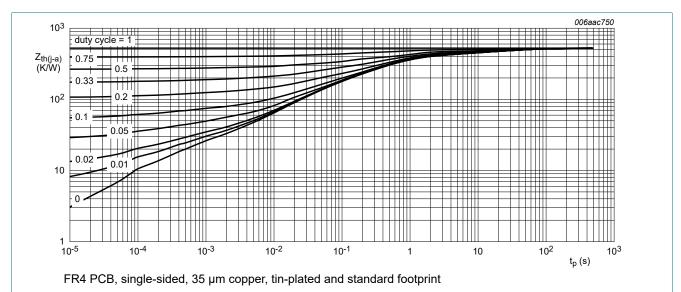


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

1 October 2022

PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

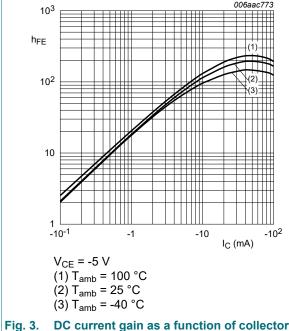
10. Characteristics

Table 7. Characteristics

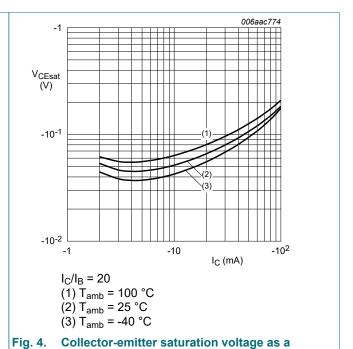
 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
$V_{(BR)CBO}$	collector-base breakdown voltage	C = -100 μA; I _E = 0 A -50		-	-	V	
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -2 mA; I _B = 0 A		-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A		-	-	-1	μΑ
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A		-	-	-400	μA
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -5 mA		-30	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = -10 mA; I _B = -0.5 mA		-	-	-100	mV
V _{I(off)}	off-state input voltage	V _{CE} = -5 V; I _C = -100 μA		-	-1.1	-0.8	V
V _{I(on)}	on-state input voltage	V _{CE} = -0.3 V; I _C = -10 mA		-2.5	-1.8	-	V
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz		-	-	3	pF
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz	[2]	-	180	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor

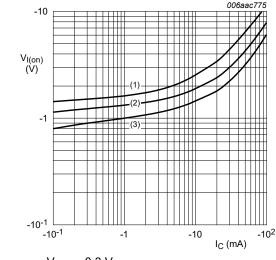




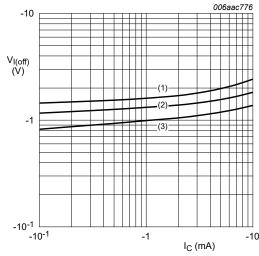


function of collector current; typical values

PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω



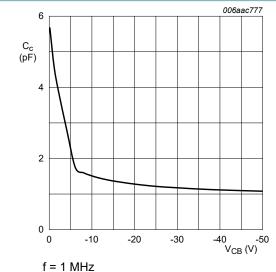
V_{CE} = -0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C



V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

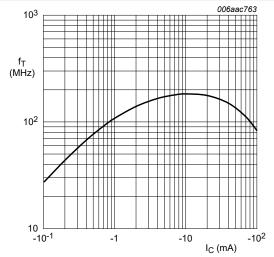
Fig. 5. On-state input voltage as a function of collector | Fig. 6. current; typical values





 T_{amb} = 25 °C

Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values



f = 100 MHz

 $T_{amb} = 25 \, ^{\circ}C$

 $V_{CE} = -5 V$

Transition frequency as a function of collector Fig. 8. current; typical values of built-in transistor

PUMB11

PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

11. Test information

Nexperia

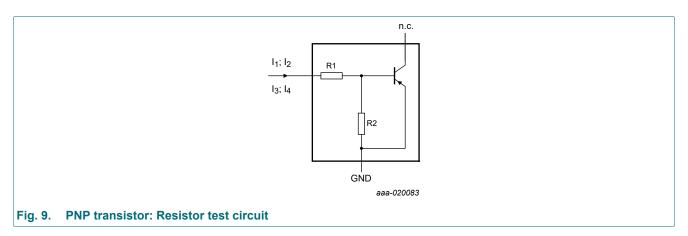
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

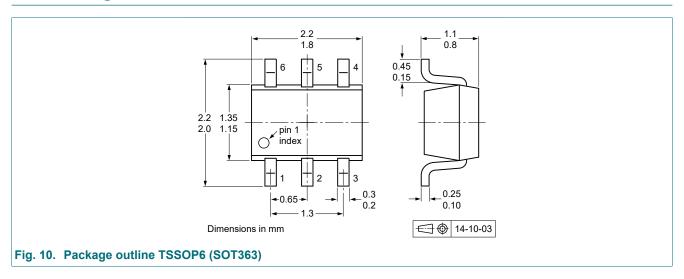


Resistor test conditions

Table 8 Resistor test conditions

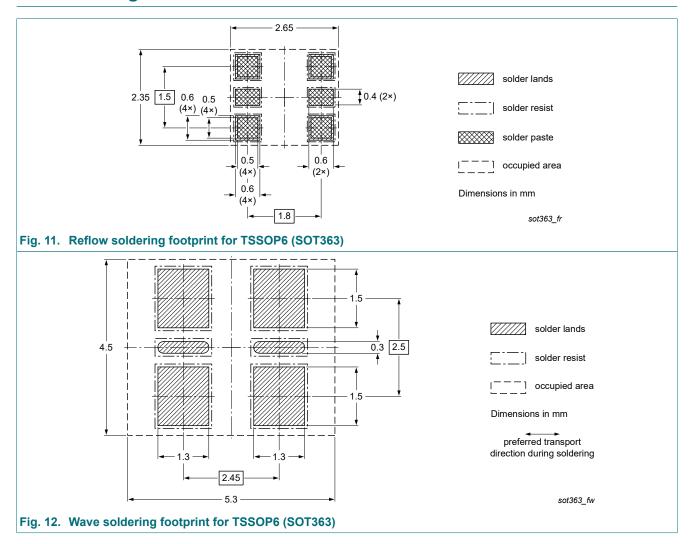
Table 6. Resistor test conditions									
PUMB11	R1 (kΩ)	R2 (kΩ)	Test conditions				Test conditions		
			I ₁	l ₂	l ₃	14			
TR1 (PNP)	10	10	-350 μΑ	-450 μA	350 μΑ	450 μA			
TR2 (PNP)	10	10	-350 μΑ	-450 μΑ	350 µA	450 µA			

12. Package outline



PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

13. Soldering



PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

14. Revision history

Table 9. Revision history

Table 5. Revision History						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PUMB11 v.5	20221001	Product data sheet	-	PEMB11_PUMB11 v.4		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Family data sheet reduced to single type data sheet. Product changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). Packing information is removed. 					
PEMB11_PUMB11 v.4	20111130	Product data sheet	-	PEMB11_PUMB11 v.3		
PEMB11_PUMB11 v.3	20031003	Product data sheet	-	PUMB11 v.2		
PUMB11 v.2	20010913	Preliminary specification	-	PUMB11 v.1		
PUMB11 v.1	20000808	Product specification	-	-		

PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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PUMB1

PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

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1 October 2022

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